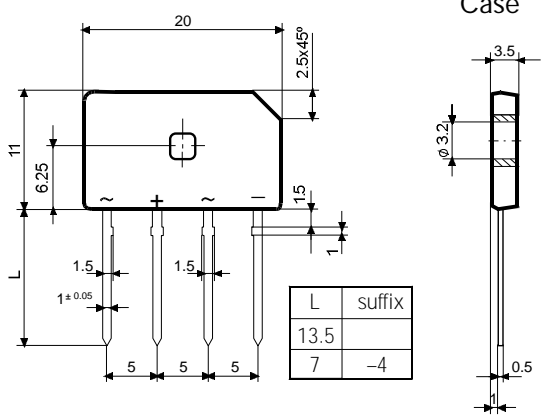
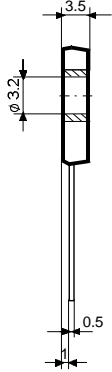



2. Amp. Glass Passivated Bridge Rectifier

| <p>Dimensions in mm.</p>  <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>L</th> <th>Suffix</th> </tr> </thead> <tbody> <tr> <td>13.5</td> <td></td> </tr> <tr> <td>7</td> <td>-4</td> </tr> </tbody> </table> <p>• Mounting Instructions</p> <ul style="list-style-type: none"> • High temperature soldering guaranteed: 260 °C – 10 sc. • Recommended mounting torque: 8 Kg.cm. | L | Suffix | 13.5 | | 7 | -4 | <p>Plastic Case</p>  | <p>Voltage 100 to 1000 V.</p> <p>Current 2.0 A.</p>  |
|--|--------|--------|------|--|---|----|---|--|
| L | Suffix | | | | | | | |
| 13.5 | | | | | | | | |
| 7 | -4 | | | | | | | |
| <p>• Glass Passivated Junction Chips.</p> <ul style="list-style-type: none"> • UL recognized under component index file number E130180. • Lead and polarity identifications. • Case: Molded Plastic. • Ideal for printed circuit board (P.C.B.). • The plastic material carries U/L recognition 94 V-O. | | | | | | | | |

Maximum Ratings, according to IEC publication No. 134

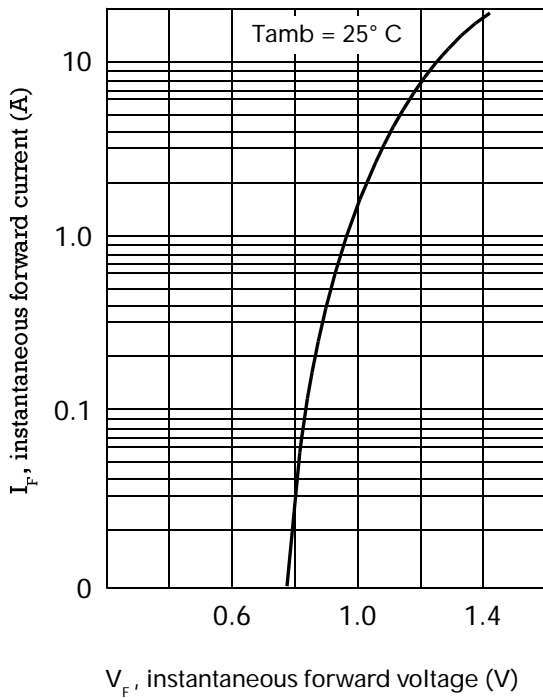
| | | FBI2B 5S2 | FBI2D 5S2 | FBI2F 5S2 | FBI2J 5S2 | FBI2L 5S2 | FBI2M 5S2 |
|-------------|--|----------------------------------|--------------|--------------|--------------|--------------|--------------|
| V_{RRM} | Peak Recurrent Reverse Voltage (V) | 100 | 200 | 300 | 600 | 900 | 1000 |
| V_{RMS} | Maximum RMS Voltage (V) | 70 | 140 | 210 | 420 | 630 | 700 |
| V_R | Recommended Input Voltage (V) | 40 | 80 | 125 | 250 | 380 | 500 |
| $I_{F(AV)}$ | Max. Average forward current with heatsink without heatsink | 4.5 A at 65 °C 2.0 A at 25 °C | | | | | |
| I_{FRM} | Recurrent peak forward current | 15 A | | | | | |
| I_{FSM} | 10 ms. peak forward surge current | 100 A | | | | | |
| I^2t | I^2t value for fusing (t = 10 ms) | 50 A ² sec | | | | | |
| V_{DIS} | Dielectric strength (terminals to case, AC 1 min.) | 1500 V | | | | | |
| T_j | Operating temperature range | - 40 to + 150 °C | | | | | |
| T_{stg} | Storage temperature range | - 40 to +150 °C | | | | | |

Electrical Characteristics at Tamb = 25°C

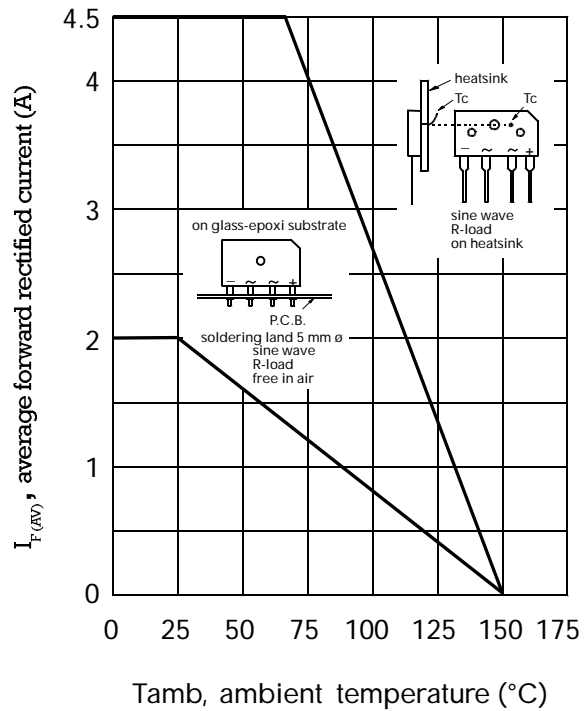
| | | |
|---------------|---|-----------|
| V_F | Max. forward voltage drop per element at $I_F = 3$ A | 1.1 V |
| I_R | Max. reverse current per element at V_{RRM} | 5 μ A |
| $R_{th(j-c)}$ | MAXIMUM THERMAL RESISTANCE Junction-Case. With Heatsink. | 12 °C/W |
| $R_{th(j-a)}$ | Junction-Ambient. Without Heatsink. | 40 °C/W |

Characteristic Curves

TYPICAL FORWARD CHARACTERISTIC



FORWARD CURRENT DERATING CURVE



MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

